

MBR1040F thru MBR10200F

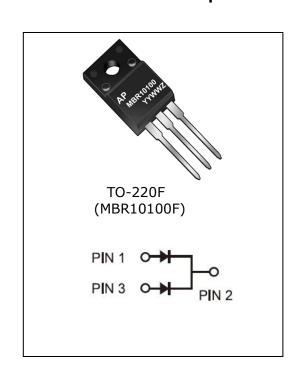
Schottky Barrier Rectifier Reverse Voltage 40 to 200 Volts Forward Current 10 Amperes

Features

- Metal silicon junction majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- For use in low voltage, high frequency inverters, free-wheeling, and polarity protection application



Case: JEDEC ITO-220 molded plastic body
Terminals: Plated axial leads, solderable
per MIL-STD-750, method 2026



Maximum Ratings Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter		Symbol	MBR 1040	MBR 1045	MBR 1060	MBR 1080	MBR 10100	MBR 10120	MBR 10150	MBR 10200	Unit
Maximum Repetitive Peak Reverse Voltage			40	50	60	80	100	120	150	200	V
Maximum RMS voltage			28	31.5	42	56	70	84	105	140	V
Maximum DC Blocking Voltage			40	45	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) lead length		I _{F(AV)}	10.0							А	
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load		I _{FSM}	150						А		
Maximum instantaneous forward voltage at 1/2I _{F(AV)}		V _F	0.	55	0.	75	0.8	35	0.90	0.95	V
Maximum DC Reverse Current	T _a = 25℃		0.5			0.1					
t Rated DC Blocking Voltage $T_a = 100^{\circ}C$		I _R	50 10					mA			
Typical Thermal Resistance ⁽²⁾		$R_{\theta JC}$	2						°C/W		
Operating and Storage Temperature Range		T _J , T _{STG}	-65 to +150							°C	

Note

- (1) Single phase, half wave, 60HZ, resistive or inductive load. For capacitive load, derate current by 20%.
- (2) PCB mounted with 0.2X0.2"(5.0X5.0 mm) copper pad areas.

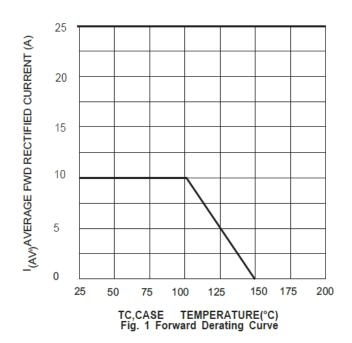
REV. 00

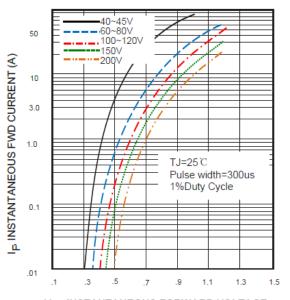


MBR1040F thru MBR10200F

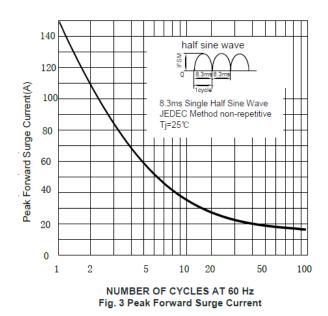
Characteristics Curves

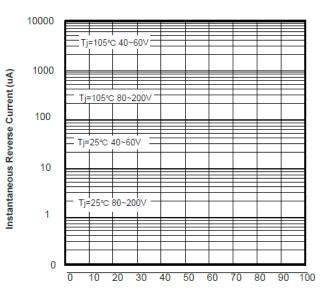
($TA = 25^{\circ}C$ unless otherwise specified)





V _F, INSTANTANEOUS FORWARD VOLTAGE
(V) Fig. 2 Typical Forward Characteristics



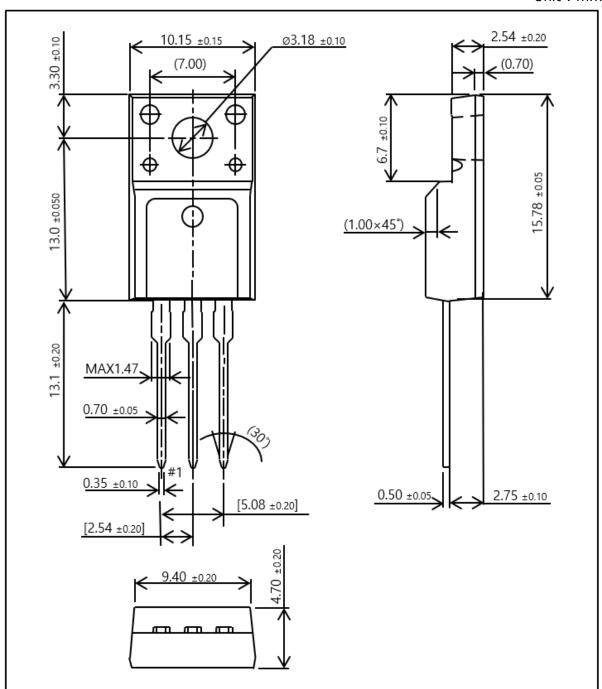


PERCENT OF RATED PEAK REVERSE VOLTAGE,(%)
FIG.4-TYPICAL FORWARD CHARACTERISTICS



Package Dimensions

Unit: mm





MBR1040F thru MBR10200F

Revision History

No	Date	Contents			
0	2021-06-08	Initial Brief Datasheet Release			

http://www.apsemi.com

IMPORTANT NOTICE

AP Semiconductor co, Ltd reserves the right to make changes without further notice to any products or specifications herein. AP Semiconductor co, Ltd does not assume any responsibility for use of any its products for any particular purpose, nor does AP Semiconductor co, Ltd assume any liability arising out of the application or use of any its products or circuits. AP Semiconductor co, Ltd does not convey any license under its patent rights or other rights nor the rights of others.

AP Semiconductor Co., Ltd

Contact. Tel 82.70.4693.2299 FAX 82.70.4000.4009

E-mail: sales@apsemi.com

© 2015 AP semiconductor Co., Ltd. –Printed in KOREA –All Rights Reserved.

REV. 00